S1FLB-M, S1FLD-M, S1FLG-M, S1FLJ-M, S1FLK-M, S1FLM-M

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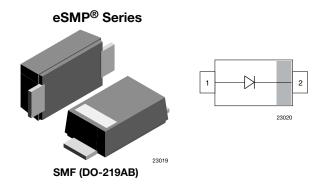
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RoHS

COMPLIANT

HALOGEN

Standard Recovery Rectifier, High Voltage Surface Mount



LINKS TO ADDITIONAL RESOURCES



SHAY

FEATURES

- · For surface mounted applications
- Low profile package
- · Ideal for automated placement
- Glass passivated
- High temperature soldering: 260 °C / 10 s at terminals
- Wave and reflow solderable
- FREE • Compatible to SOD-123W package case outline or SOD-123F and SOD-123FL
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

MECHANICAL DATA

Case: SMF (DO-219AB) Polarity: band denotes cathode end Weight: approx. 15 mg Packaging codes / options: 18/10K per 13" reel (8 mm tape), MOQ = 50K 08/3K per 7" reel (8 mm tape), MOQ = 30K Circuit configuration: single

PARTS TABLE						
PART	ORDERING CODE	MARKING	REMARKS			
S1FLB-M	S1FLB-M-18 or S1FLB-M-08	HB	Tape and reel			
S1FLD-M	S1FLD-M-18 or S1FLD-M-08	HD	Tape and reel			
S1FLG-M	S1FLG-M-18 or S1FLG-M-08	HG	Tape and reel			
S1FLJ-M	S1FLJ-M-18 or S1FLJ-M-08	HJ	Tape and reel			
S1FLK-M	S1FLK-M-18 or S1FLK-M-08	НК	Tape and reel			
S1FLM-M	S1FLM-M-18 or S1FLM-M-08	HM	Tape and reel			

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT			
		S1FLB-M	V _{RRM}	100	V			
		S1FLD-M	V _{RRM}	200	V			
Maximum repetitive peak reverse voltage		S1FLG-M	V _{RRM}	400	V			
Maximum repetitive peak reverse voltage		S1FLJ-M	V _{RRM}	600	V			
		S1FLK-M	V _{RRM}	800	V			
		S1FLM-M	V _{RRM}	1000	V			
		S1FLB-M	V _{RMS}	70	V			
		S1FLD-M	V _{RMS}	140	V			
Maximum RMS voltage		S1FLG-M	V _{RMS}	280	V			
Maximum Rivis voltage		S1FLJ-M	V _{RMS}	420	V			
		S1FLK-M	V _{RMS}	560	V			
		S1FLM-M	V _{RMS}	700	V			

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT			
		S1FLB-M	V _{DC}	100	V			
Maximum DC blocking voltage		S1FLD-M	V _{DC}	200	V			
		S1FLG-M	V _{DC}	400	V			
		S1FLJ-M	V _{DC}	600	V			
		S1FLK-M	V _{DC}	800	V			
		S1FLM-M	V _{DC}	1000	V			
	$T_{L} = 75 \ ^{\circ}C \ ^{(1)}$		I _{F(AV)}	1.5	A			
Maximum average forward rectified current	T_A = 25 °C $^{(1)}$ at R_{thJA} $<$ 110 K/W		I _{F(AV)}	1	А			
	$T_A = 65 \ ^{\circ}C \ ^{(1)}$		I _{F(AV)}	0.7	A			
Peak forward surge current 8.3 ms half sine-wave	T _L = 25 °C		I _{FSM}	22	A			

Note

SHAY

⁽¹⁾ Averaged over any 20 ms period

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
Thermal resistance junction to ambient air ⁽¹⁾		R _{thJA}	180	K/W				
Operating junction and storage temperature range		T _j , T _{stg}	-55 to +150	°C				

Note

 $^{(1)}$ Mounted on epoxy substrate with 3 mm x 3 mm Cu pads (\geq 40 μm thick)

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	1 A ⁽¹⁾	S1FLB-M	V _F			1.1	V	
		S1FLD-M	V _F			1.1	V	
Instantanceus ferward voltage		S1FLG-M	V _F			1.1	V	
Instantaneous forward voltage		S1FLJ-M	V _F			1.1	V	
		S1FLK-M	V _F			1.1	V	
		S1FLM-M	V _F			1.1	V	
	T _A = 25 °C	S1FLB-M	I _R			10	μA	
		S1FLD-M	I _R			10	μA	
		S1FLG-M	I _R			10	μA	
		S1FLJ-M	I _R			10	μA	
		S1FLK-M	I _R			10	μA	
Maximum DC reverse current at rated		S1FLM-M	I _R			10	μA	
DC blocking voltage	T 405.00	S1FLB-M	I _R			50	μA	
		S1FLD-M	I _R			50	μA	
		S1FLG-M	I _R			50	μA	
	T _A = 125 °C	S1FLJ-M	I _R			50	μA	
		S1FLK-M	I _R			50	μA	
		S1FLM-M	I _R			50	μA	

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A	S1FLB-M	t _{rr}			1800	ns	
		S1FLD-M	t _{rr}			1800	ns	
Bayaraa raaayany tima		S1FLG-M	t _{rr}			1800	ns	
Reverse recovery time		S1FLJ-M	t _{rr}			1800	ns	
		S1FLK-M	t _{rr}			1800	ns	
		S1FLM-M	t _{rr}			1800	ns	
	4 V, 1 MHz	S1FLB-M	Cj		4		pF	
		S1FLD-M	Cj		4		pF	
Turriant conceitones		S1FLG-M	Cj		4		pF	
Typical capacitance		S1FLJ-M	Cj		4		pF	
		S1FLK-M	Cj		4		pF	
		S1FLM-M	Cj		4		pF	

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

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TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

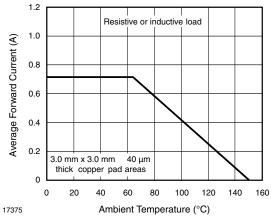


Fig. 1 - Forward Current Derating Curve

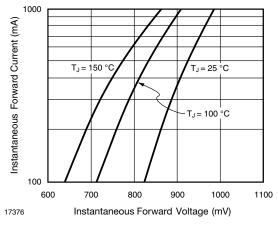


Fig. 2 - Typical Instantaneous Forward Characteristics

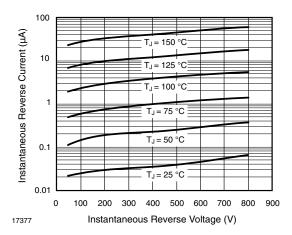
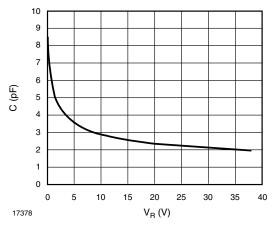
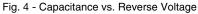


Fig. 3 - Typical Instantaneous Reverse Characteristics



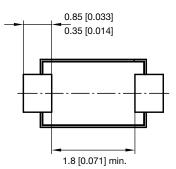


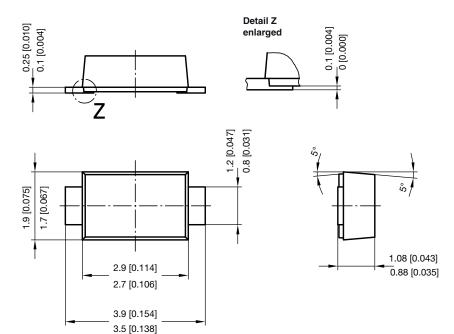
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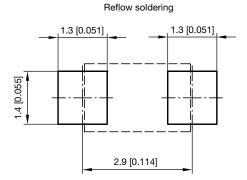
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PACKAGE DIMENSIONS in millimeters (inches): SMF (DO-219AB)





foot print recommendation:



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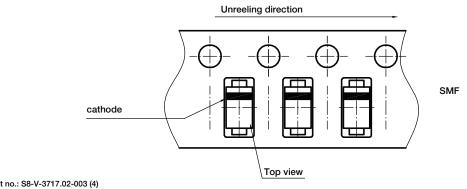
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ORIENTATION IN CARRIER TAPE - SMF (DO-219AB)



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